NSN 5961-01-269-1736

Thyristor Semiconductor Device - Page 1 of 1



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Special Features:

Matl: silicon; configuration: junction contact; junction configuration: pnpn; max. Working voltage: 400v; operating temp: -40c to +110c; rms forward on-state current: 4 amps max.; peak forward on-state repetitive current: 75 amps; peak on voltage: 2.2 volts maximum at 4 amps; inclosure matl: plastic; jedec case outline designation: to-202; mounting method: unthreaded hole; terminal type: 3 uninsulated wire lead; thyristor lengt (including mounting plate): .835 in. Max; height: .190 in. Max; width: .400 in. Max; repair part for 6515-01-246-1938, suction apparatus, surgical, model 6003 by gomco

N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	

Shelf Life:

A110a0